

SILICON POWER TRANSISTOR 2SB1431

PNP SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR LOW-FREQUENCY POWER AMPLIFIERS AND LOW-SPEED SWITCHING

The 2SB1431 is a Darlington power transistor that can directly drive from the IC output. This transistor is ideal for motor drivers and solenoid drivers in such as OA and FA equipment.

In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

FEATURES

- High here due to Darlington connection: here $\geq 2,000$ (Vce = -2 V, lc = -3 A)
- Mold package that does not require an insulating board or insulation bushing

QUALITY GRADES

Standard

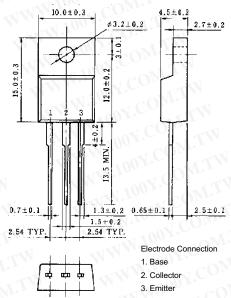
Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

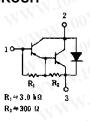
Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	–100	V
Collector to emitter voltage	VCEO	-100	V
Emitter to base voltage	VEBO	-7.0	V
Collector current (DC)	Ic(DC)	-8.0	Α
Collector current (pulse)	IC(pulse)*	-12	Α
Base current (DC)	I _{B(DC)}	-0.8	Α
Total power dissipation	Рт (Tc = 25°C)	25	W
Total power dissipation	P⊤ (Ta = 25°C)	2.0	W
Junction temperature	TV.100	150	°C
Storage temperature	Tstg	-55 to +150	°C

^{*} PW \leq 10 ms, duty cycle \leq 50%

PACKAGE DRAWING (UNIT: mm)



EQUIVALENT CIRCUIT



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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	V _{CB} = -100 V, I _E = 0		Lin	-1.0	μΑ
DC current gain	h _{FE1} *	V _{CE} = -2.0 V, I _C = -3.0 A	2,000	WILL	15,000	
DC current gain	hFE2*	Vce = -2.0 V, Ic = -5.0 A	500	M.T.V		
Collector saturation voltage	VcE(sat)*	Ic = -3.0 A, I _B = -3.0 mA	1001	-0.9	-1.5	V
Base saturation voltage	V _{BE(sat)} *	Ic = -3.0 A, Iв = -3.0 mA	100Y.	-1.6	-2.0	V
Gain bandwidth product	fτ	Vce = -5.0 V, Ic = -0.8 A	-1100X	80	TW	MHz
Collector capacitance	Cob	V _{CB} = -10 V, I _E = 0, f = 1.0 MHz	100	80	WI	pF
Turn-on time	ton	$I_C = -3.0 \text{ A}, I_{B1} = -I_{B2} = -3.0 \text{ mA},$	111.	0.5	WT	μs
Storage time	tstg	R _L = 16.7 Ω , Vcc \cong -50 V Refer to the test circuit.	WW.I	1.0	WIT	μs
Fall time	t _f	Refer to the test circuit.	T.WW.I	1.0	Dir	μs

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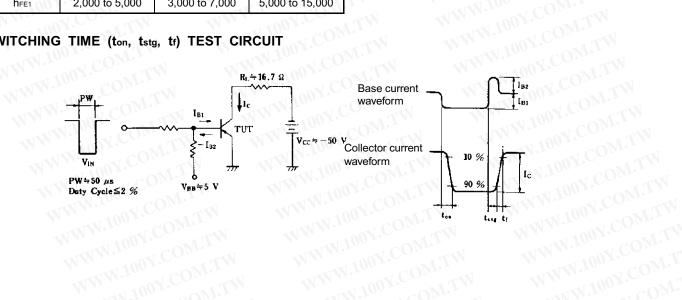
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hfe CLASSIFICATION

* Pulse test F	$PW \le 350 \mu s$, duty	cycle ≤ 2%	
hre CLASS	IFICATION		
Marking	M	The state of the s	M.
h _{FE1}	2,000 to 5,000	3,000 to 7,000	5,000 to 15,000

SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

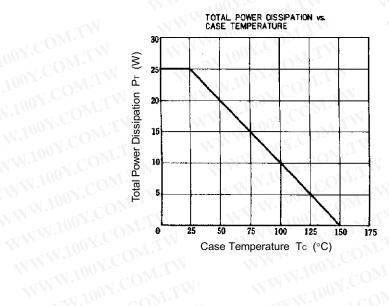


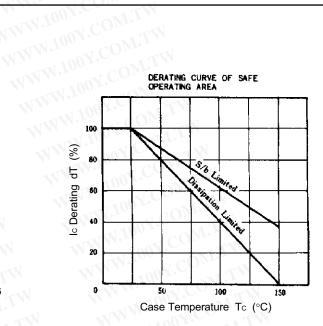
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^{*} Pulse test PW \leq 350 μ s, duty cycle \leq 2%

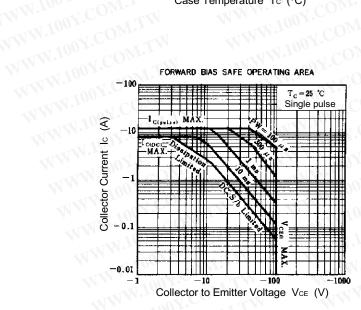


TYPICAL CHARACTERISTICS (Ta = 25°C)



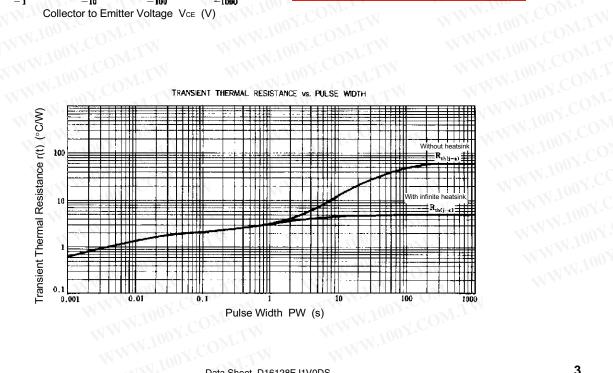


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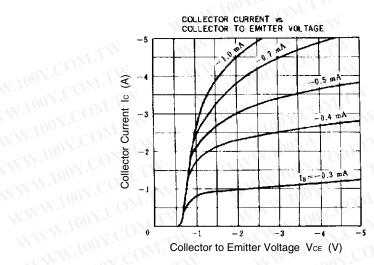
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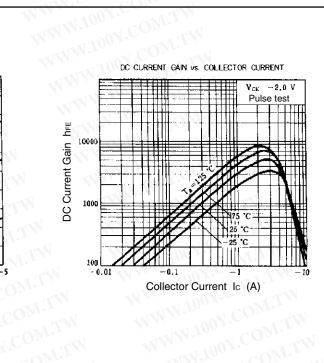


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Data Sheet D16128EJ1V0DS

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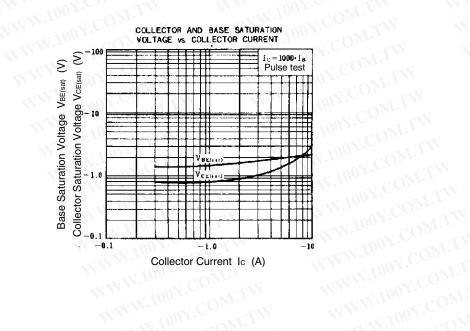




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